Hyperfast Rectifier, 30 A FRED Pt[®] G5



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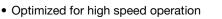
LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I _{F(AV)}	30 A							
V _R	600 V							
V _F at I _F at 125 °C	1.15 V							
t _{rr} (typ.)	25 ns							
T _J max.	175 °C							
Package	D ² PAK 2L (TO-263AB 2L)							
Circuit configuration	Single							

FEATURES

· Best in class forward voltage drop and switching losses trade off



- HALOGEN 175 °C maximum operating junction temperature
- Polyimide passivation
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

MECHANICAL DATA

Case: D²PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 113 °C, D = 0.50	30	A						
Repetitive peak forward current	I _{FRM}	T _C = 113 °C, D = 0.50, f = 20 kHz	60							
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	330							
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS					UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-				
Forward voltage	V _F	I _F = 30 A	-	1.3	1.6	V			
Forward voltage		I _F = 30 A, T _J = 125 °C	-	1.15	-				
Deverse leakage eurrent	I _R	V _R = V _R rated	-	-	20				
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ -		-	500	μA			
Junction capacitance	CT	V _R = 200 V	-	36	-	pF			
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH			

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COMPLIANT

FREE



DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS				
		$I_F = 1.0 \text{ A,d}I_F/\text{dt} =$	$I_F = 1.0 \text{ A,d}I_F/\text{dt} = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	41	-	ns			
		T _J = 125 °C		-	58	-				
Pook receivery ourrent		T _J = 25 °C	$I_F = 20 A$	-	19	-	A			
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 1000 A/µs V _B = 400 V	-	32	-				
	Q _{rr}	T _J = 25 °C		-	419	-	nC			
Reverse recovery charge		T _J = 125 °C		-	1176	-				
Reverse recovery time	+	T _J = 25 °C		-	46	-	ns A nC			
Reverse recovery lime	t _{rr}	T _J = 125 °C		-	65	-				
Pook receivery ourrent	I _{RRM}	T _J = 25 °C	I _F = 30 A dI _F /dt = 1000 A/µs	-	21	-				
Peak recovery current		T _J = 125 °C	$V_{\rm R} = 400 \text{V}$	-	36	-				
Davience ne constructione		T _J = 25 °C]	-	550	-				
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1560	-	nc			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN. TYP. MAX. UNIT							
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.3	°C/W				
Weight			-	2.0	-	g				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style D ² PAK 2L (TO-263AB 2L)	E5TH3006S							



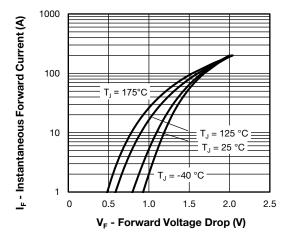


Fig. 1 - Typical Forward Voltage Drop Characteristics, Per Leg

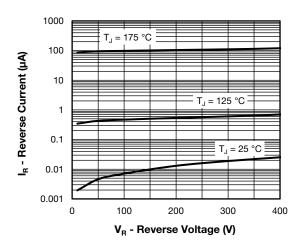
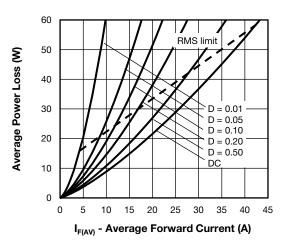
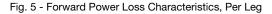


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg





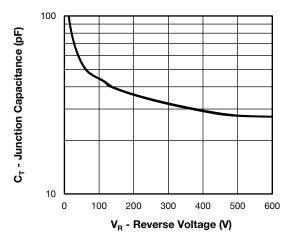
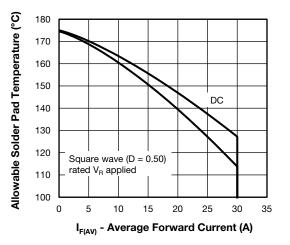
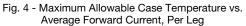


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg





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 3
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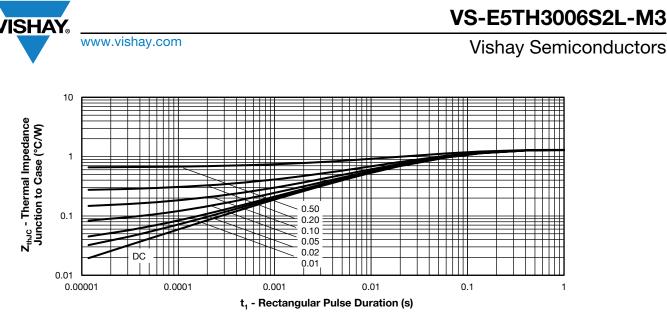


Fig. 6 - Transient Thermal Impedance, Junction to Case, Per Leg

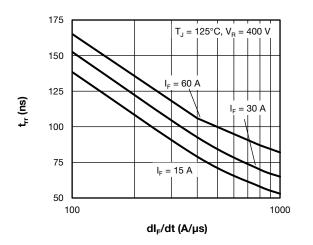


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

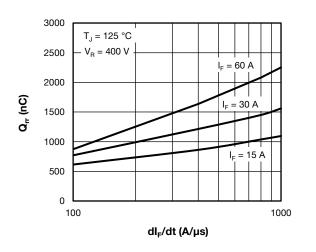


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

45 T_J = 125 °C = 60 A 40 V_R = 400 V 35 I_F = 30 A 30 ا_ت (ک 25 20 I_{F} = 15 A 15 10 5 100 1000 dl_F/dt (A/µs)

Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

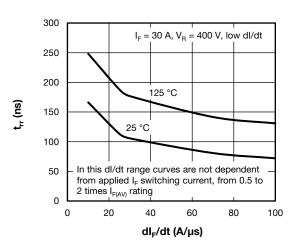


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

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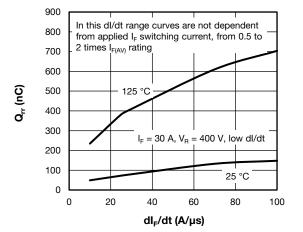
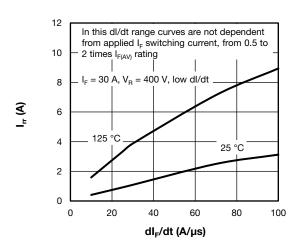


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg



VS-E5TH3006S2L-M3

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Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

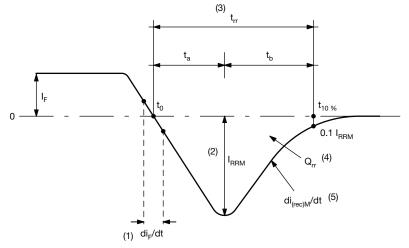


Fig. 13 - Reverse Recovery Waveform and Definitions

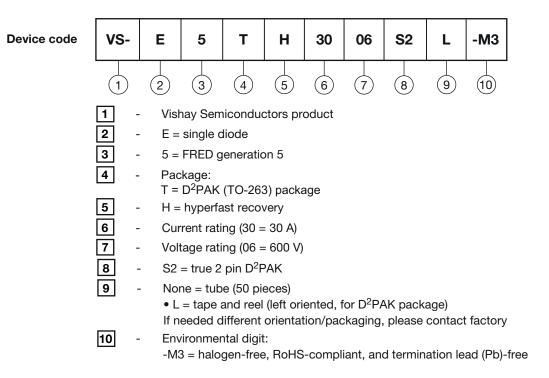
Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~\text{Q}_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

⁽⁵⁾ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)								
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION								
VS-E5TH3006S2L-M3	800	13" diameter reel						

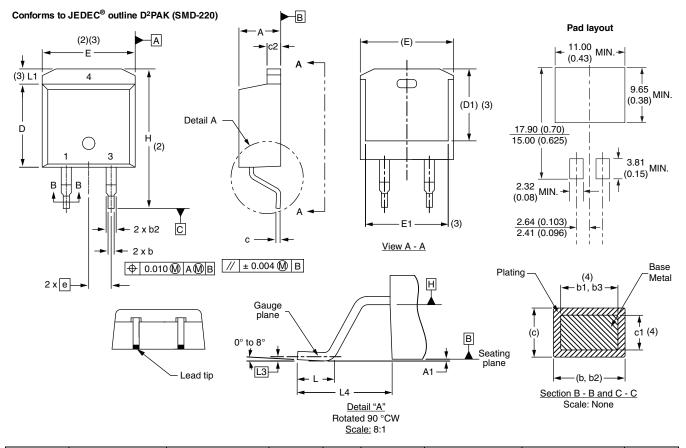
LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96683
Part marking information	www.vishay.com/doc?96693
Packaging information	www.vishay.com/doc?95032
SPICE model	www.vishay.com/doc?96919





D²PAK 2L (TO-263AB 2L)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES		NOTES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3	
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3	
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3	
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC		
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625		
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110		
с	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3	
c1	0.38	0.58	0.015	0.023	4		L3	0.25 BSC		0.010	BSC		
c2	1.14	1.65	0.045	0.065			L4	4.78	5.28	0.188	0.208		
D	8.51	9.65	0.335	0.380	2								

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
 (3) Thermal and contain antional within dimension E 1.1, D1 and E1.

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

(7) Outline conforms to JEDEC® outline TO-263AB

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1

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